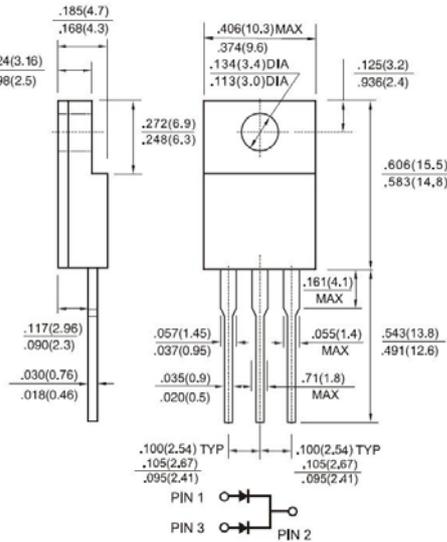




MBRF20H100CT - MBRF20H200CT
10.0AMPS Isolated Schottky Barrier Rectifiers
ITO-220AB

Features

- ✧ UL Recognized File # E-326243
- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Metal silicon junction, majority carrier conductor
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guard-ring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.25", (6.35mm) from case
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode



Mechanical Data

- ✧ Case: ITO-220AB molded plastic body
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs, max
- ✧ Weight: 1.75 grams

Dimensions in inches and (millimeters)

Marking Diagram



- MBRF20HXXCT = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 20H100CT	MBRF 20H150CT	MBRF 20H200CT	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	150	200	V
Maximum RMS Voltage	V_{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	100	150	200	V
Maximum Average Forward Rectified Current at $T_C=133^\circ\text{C}$	$I_{F(AV)}$	20			A
Peak Repetitive Surge Current (Rated V_R , Square Wave, 20KHz) at $T_C=133^\circ\text{C}$	I_{FRM}	20			A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	150			A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1		0.5	A
Maximum Instantaneous Forward Voltage (Note 2) $I_F=10\text{A}, T_A=25^\circ\text{C}$ $I_F=10\text{A}, T_A=125^\circ\text{C}$ $I_F=20\text{A}, T_A=25^\circ\text{C}$ $I_F=20\text{A}, T_A=125^\circ\text{C}$	V_F	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Reverse Current @ Rated V_R $T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	I_R	5 2			μA mA
Voltage Rate of Change, (Rated V_R)	dV/dt	10000			V/us
RMS Isolation Voltage (t=1.0 second, R.H. $\leq 30\%$, $T_A=25^\circ\text{C}$)	V_{ISO}	4500 (Note 3) 3500 (Note 4) 1500 (Note 5)			V
Typical Thermal Resistance	$R_{\theta JC}$	3.5			$^\circ\text{C/W}$
Operating Temperature Range	T_J	- 65 to + 175			$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 65 to + 175			$^\circ\text{C}$

Note 1: 2.0uS Pulse Width, $f=1.0\text{KHz}$

Note 2: Pulse Test : 300uS Pulse Width, 1% Duty Cycle

Note 3: Clip Mounting (on case), where lead does not overlap heatsink with 0.11" offset

Note 4: Clip Mounting (on case), where lead do overlap heatsink.

Note 5: Screw mounting with 4-40 screw, where washer diameter is $\leq 4.9\text{mm}$ (0.19")

RATINGS AND CHARACTERISTIC CURVES (MBRF20H100CT THRU MBRF20H200CT)

FIG. 1 FORWARD CURRENT DERATING CURVE

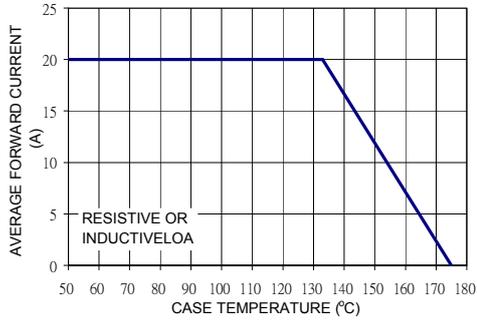


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

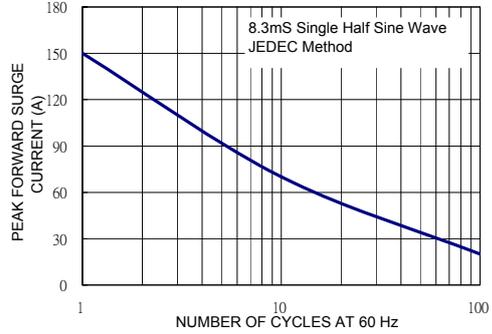


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

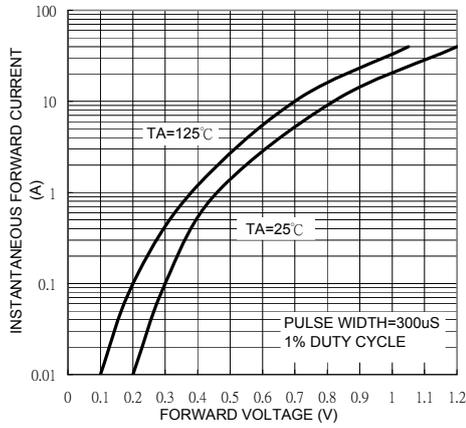


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

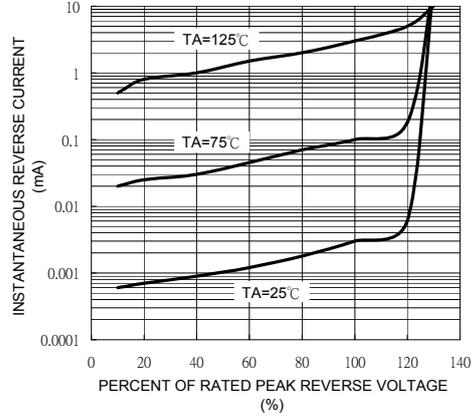


FIG. 5 TYPICAL JUNCTION CAPACITANCE

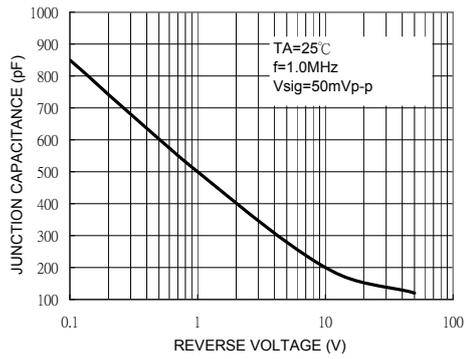


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE

